74AHC573-Q100; 74AHCT573-Q100

Octal D-type transparent latch; 3-state Rev. 2 — 13 July 2020

Product data sheet

1. General description

The 74AHC573-Q100; 74AHCT573-Q100 is an 8-bit D-type transparent latch with 3-state outputs. The device features latch enable (LE) and output enable (\overline{OE}) inputs. When LE is HIGH, data at the inputs enter the latches. In this condition the latches are transparent, a latch output will change each time its corresponding D-input changes. When LE is LOW the latches store the information that was present at the inputs a set-up time preceding the HIGH-to-LOW transition of LE. A HIGH on \overline{OE} causes the outputs to assume a high-impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the latches. Inputs are overvoltage tolerant. This feature allows the use of these devices as translators in mixed voltage environments.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)

 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 5.5 V
- · Balanced propagation delays
- All inputs have Schmitt-trigger action
- Overvoltage tolerant inputs to 5.5 V
- High noise immunity
- CMOS low power dissipation
- Common 3-state output enable input
- Input levels:
 - For 74AHC573-Q100: CMOS input level
 - For 74AHCT573-Q100: TTL input level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
 - Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

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3. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AHC573D-Q100	-40 °C to +125 °C	SO20	plastic small outline package; 20 leads;	SOT163-1
74AHCT573D-Q100			body width 7.5 mm	
74AHC573PW-Q100	-40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package;	SOT360-1
74AHCT573PW-Q100			20 leads; body width 4.4 mm	
74AHC573BQ-Q100	-40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible	SOT764-1
74AHCT573BQ-Q100			thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	

4. Functional diagram

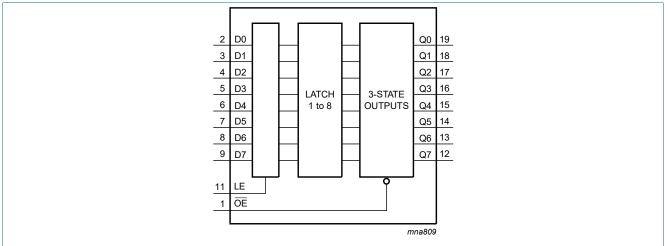
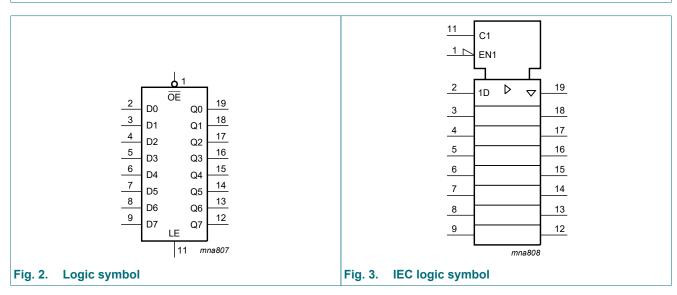
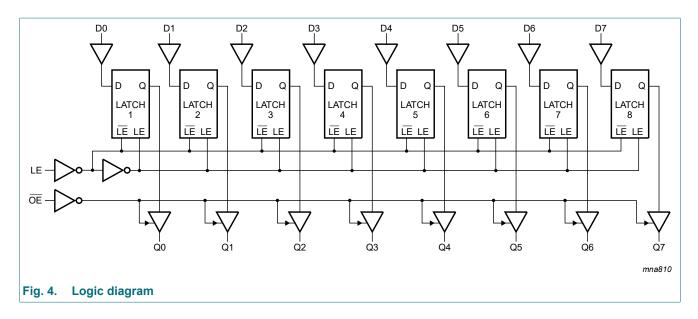


Fig. 1. Functional diagram

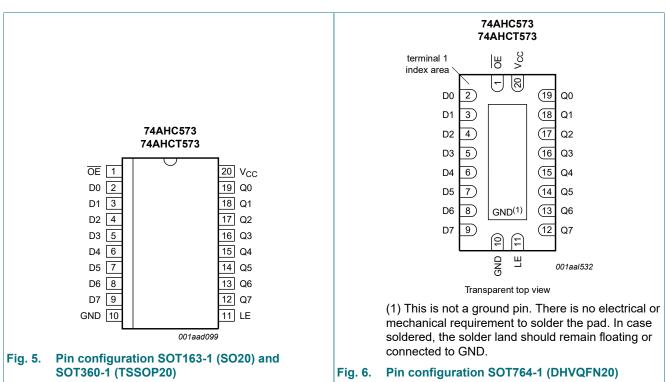


74AHC573-Q100; 74AHCT573-Q100

Octal D-type transparent latch; 3-state



5. Pinning information



5.1. Pinning

5.2. Pin description

Table 2. Pin description		
Symbol	Pin	Description
OE	1	output enable input (active LOW)
D0 to D7	2, 3, 4, 5, 6, 7, 8, 9	data input
GND	10	ground (0 V)
LE	11	latch enable (active HIGH)
Q0 to Q7	19, 18, 17, 16, 15, 14, 13, 12	data output
V _{CC}	20	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; *h* = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition;

Z = high-impedance OFF-state.

Operating mode	Input			Internal latch	Output
	OE	LE	Dn		Qn
Enable and read register (transparent mode)	L	Н	L	L	L
			Н	Н	Н
Latch and read register	L	L	I	L	L
			h	Н	Н
Latch register and disable outputs	Н	L	I	L	Z
			h	Н	Z

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7.0	V
VI	input voltage			-0.5	+7.0	V
l _{IK}	input clamping current	V ₁ < -0.5 V	[1]	-20	-	mA
I _{OK}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-20	+20	mA
lo	output current	$V_{\rm O}$ = -0.5 V to (V _{CC} + 0.5 V)		-25	+25	mA
I _{CC}	supply current			-	+75	mA
I _{GND}	ground current			-75	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT163-1 (SO20) package: P_{tot} derates linearly with 12.3 mW/K above 109 °C.

For SOT360-1 (TSSOP20) package: P_{tot} derates linearly with 10.0 mW/K above 100 °C.

For SOT764-1 (DHVQFN20) package: P_{tot} derates linearly with 12.9 mW/K above 111 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74AHC573-Q100			74AI	Unit		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	-	-	100	-	-	-	ns/V
	fall rate	V _{CC} = 5.0 V ± 0.5 V	-	-	20	-	-	20	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	-40 °	'C to +'	125 °C	Unit
			Min	Тур	Мах	Min	Max	Min	Тур	Max	1
74AHC5	73-Q100						I				1
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	-	1.65	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}									
	output voltage	I _O = -50 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	-	V
		I _O = -50 μA; V _{CC} = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	-	V
		I _O = -50 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.58	-	-	2.48	-	2.40	-	-	V
		I _O = -8.0 mA; V _{CC} = 4.5 V	3.94	-	-	3.80	-	3.70	-	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}									
	output voltage	I _O = 50 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	-	0.1	V
		I _O = 50 μA; V _{CC} = 3.0 V	-	0	0.1	-	0.1	-	-	0.1	V
		I _O = 50 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.36	-	0.44	-	-	0.55	V
		I _O = 8.0 mA; V _{CC} = 4.5 V	-	-	0.36	-	0.44	-	-	0.55	V
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or GND};$ $V_{CC} = 5.5 \text{ V}$	-	-	±0.25	-	±2.5	-	-	±10.0	μA
lı	input leakage current	V _I = V _{CC} or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	-	2.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	4.0	-	40	-	-	80	μA

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	-40 °	°C to +	125 °C	Unit
			Min	Тур	Max	Min	Мах	Min	Тур	Max	
CI	input capacitance	V _I = V _{CC} or GND	-	3	10	-	10	-	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	10	pF
74AHCT	573-Q100										
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	-	0.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$									
	output voltage	Ι _Ο = -50 μΑ	4.4	4.5	-	4.4	-	4.4	-	-	V
		I _O = -8.0 mA	3.94	-	-	3.80	-	3.70	-	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$									
	output voltage	I _O = 50 μA	-	0	0.1	-	0.1	-	-	0.1	V
		l _O = 8.0 mA	-	-	0.36	-	0.44	-	-	0.55	V
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or } GND;$ $V_{CC} = 5.5 \text{ V}$	-	-	±0.25	-	±2.5	-	-	±10.0	μA
l	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	-	2.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	4.0	-	40	-	-	80	μA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V; I _O = 0 A; other pins at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V	-	-	1.35	-	1.5	-	-	1.5	mA
CI	input capacitance	V _I = V _{CC} or GND	-	3	10	-	10	-	-	10	pF
C _O	output capacitance		-	4	-	-	-	-	-	10	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 11.

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	1
74AHC5	73-Q100						-	1		
t _{pd}	propagation	Dn to Qn; see Fig. 7 [2]								
	delay	V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	-	5.5	11.0	1.0	13.0	1.0	14.0	ns
		C _L = 50 pF	-	7.8	14.5	1.0	16.5	1.0	18.5	ns
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	3.9	6.8	1.0	8.0	1.0	8.5	ns
		C _L = 50 pF	-	5.5	8.8	1.0	10.0	1.0	11.0	ns
		LE to Qn; see Fig. 8 [2]								
		V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	-	5.8	11.9	1.0	14.0	1.0	15.0	ns
		C _L = 50 pF	-	8.3	15.4	1.0	17.5	1.0	19.5	ns
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.2	7.7	1.0	9.0	1.0	10.0	ns
		C _L = 50 pF	-	5.9	9.7	1.0	11.0	1.0	12.5	ns
t _{en}	enable time	OE to Qn; see Fig. 9 [3]								
		V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	-	5.8	11.5	1.0	13.5	1.0	14.5	ns
		C _L = 50 pF	-	8.3	15.0	1.0	17.0	1.0	19.0	ns
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.4	7.7	1.0	9.0	1.0	10.0	ns
		C _L = 50 pF	-	6.3	9.7	1.0	11.0	1.0	12.5	ns
t _{dis}	disable time	OE to Qn; see Fig. 9 [4]								
		V _{CC} = 3.0 V to 3.6 V								
		C _L = 15 pF	-	6.8	11.0	1.0	13.0	1.0	14.0	ns
		C _L = 50 pF	-	9.7	14.5	1.0	16.5	1.0	18.5	ns
		V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.6	7.7	1.0	9.0	1.0	10.0	ns
		C _L = 50 pF	-	7.4	9.7	1.0	11.0	1.0	12.5	ns
t _W	pulse width	LE HIGH; see Fig. 8								
		V _{CC} = 3.0 V to 3.6 V	5.0	-	-	5.0	-	5.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	Dn to LE; see <u>Fig. 10</u>								
		V _{CC} = 3.0 V to 3.6 V	3.5	-	-	3.5	-	3.5	-	ns
		V _{CC} = 4.5 V to 5.5 V	3.5	-	-	3.5	-	3.5	-	ns
t _h	hold time	Dn to LE; see Fig. 10								
		V _{CC} = 3.0 V to 3.6 V	1.5	-	-	1.5	-	1.5	-	ns
		V _{CC} = 4.5 V to 5.5 V	1.5	-	_	1.5	-	1.5	-	ns

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	-
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V _I = GND to V _{CC}	[5]	-	12	-	-	-	-	-	pF
74AHCT	573-Q100; V _C	_c = 4.5 V to 5.5 V								1	
t _{pd}	propagation	Dn to Qn; see Fig. 7	[2]								
	delay	C _L = 15 pF		-	3.5	5.5	1	6.5	1	7.0	ns
		C _L = 50 pF		-	4.9	7.5	1	8.5	1	9.5	ns
		LE to Qn; see Fig. 8	[2]								
		C _L = 15 pF		-	3.9	6.0	1	7.0	1	7.5	ns
		C _L = 50 pF		-	5.5	8.5	1	9.5	1	11.0	ns
t _{en}	enable time	OE to Qn; see Fig. 9	[3]								
		C _L = 15 pF		-	4.1	6.5	1	7.5	1	8.5	ns
		C _L = 50 pF		-	5.9	8.5	1	10.0	1	11.0	ns
t _{dis}	disable time	OE to Qn; see Fig. 9	[4]								
		C _L = 15 pF		-	4.5	6.5	1	7.5	1	8.5	ns
		C _L = 50 pF		-	6.4	9.0	1	10.0	1	11.5	ns
t _W	pulse width	LE HIGH; see Fig. 8		5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	Dn to LE; see Fig. 10		3.5	-	-	3.5	-	3.5	-	ns
t _h	hold time	Dn to LE; see Fig. 10		1.5	-	-	1.5	-	1.5	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V _I = GND to V _{CC}	[5]	-	18	-	-	-	-	-	pF

[1] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V and V_{CC} = 5.0 V).

[2] t_{pd} is the same as t_{PHL} and t_{PLH} .

 $[3] \quad t_{en} \text{ is the same as } t_{PZH} \text{ and } t_{PZL}.$

 $[4] \quad t_{\text{dis}} \text{ is the same as } t_{\text{PHZ}} \text{ and } t_{\text{PLZ}}.$

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

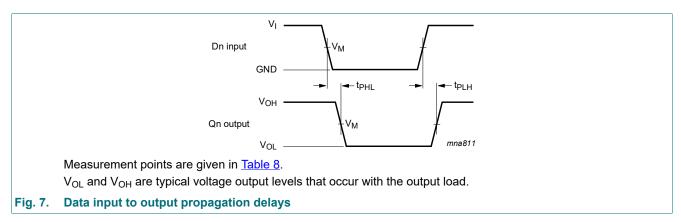
 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

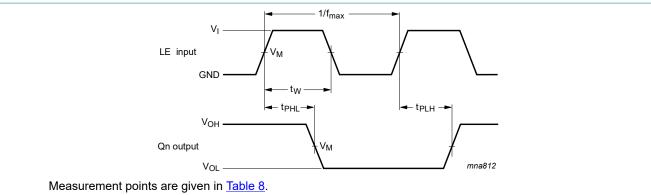
10.1. Waveforms and test circuit



74AHC_AHCT573_Q100

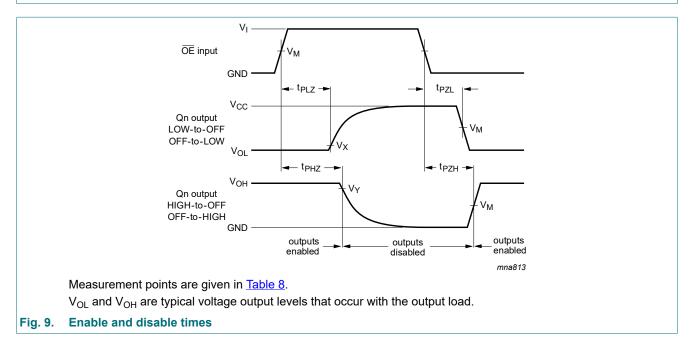
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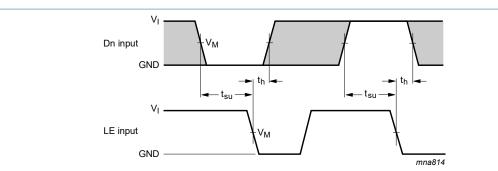
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 8. Latch enable input to output propagation delays



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Measurement points are given in <u>Table 8</u>.

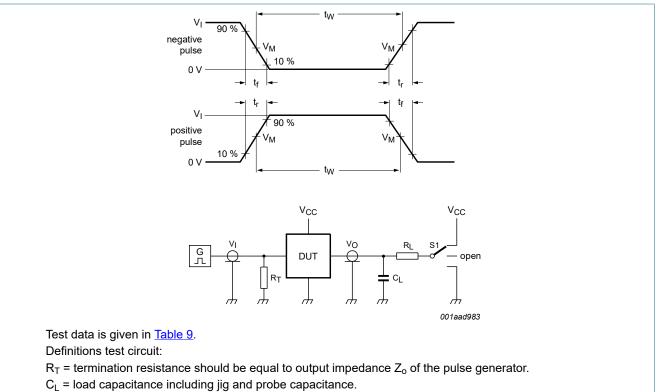
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

The shaded areas indicate when the input is permitted to change for predicable output performance.

Fig. 10. Data set-up and hold times

Table 8. Measurement points

Туре	Input	Output				
	V _M	V _M	V _X	V _Y		
74AHC573-Q100	0.5 x V _{CC}	0.5 x V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V		
74AHCT573-Q100	1.5 V	0.5 x V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V		



 $R_L = load resistance.$

S1 = test selection switch.

Fig. 11. Test circuit for measuring switching times

Table 9. Test data

Туре	Input		Load		S1 position			
	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74AHC573-Q100	V _{CC}	≤ 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	
74AHCT573-Q100	3.0 V	≤ 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	

74AHC_AHCT573_Q100

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11. Package outline

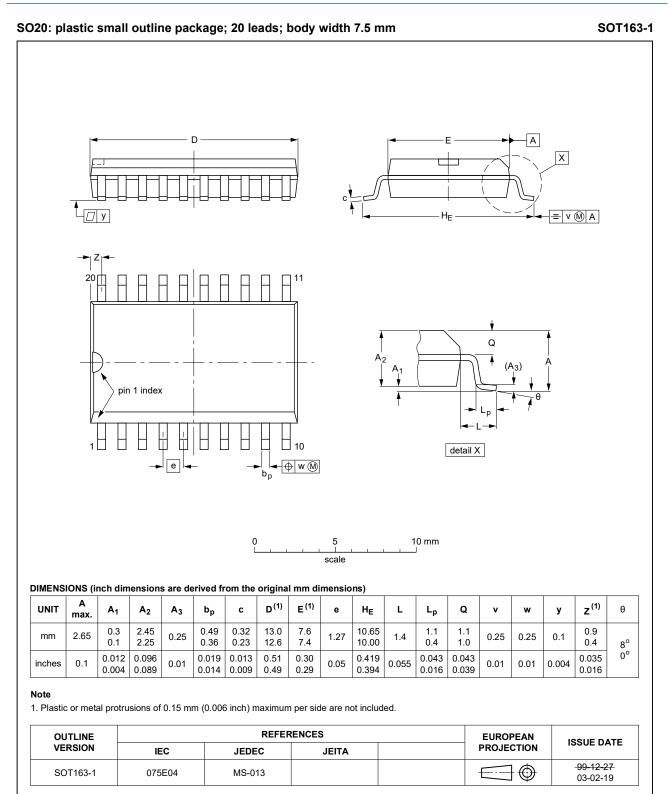


Fig. 12. Package outline SOT163-1 (SO20)

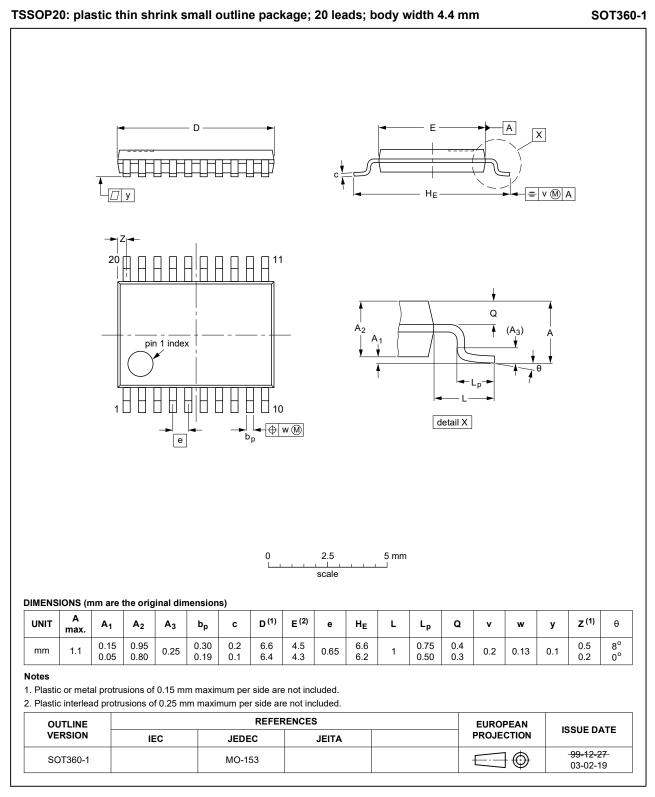


Fig. 13. Package outline SOT360-1 (TSSOP20)

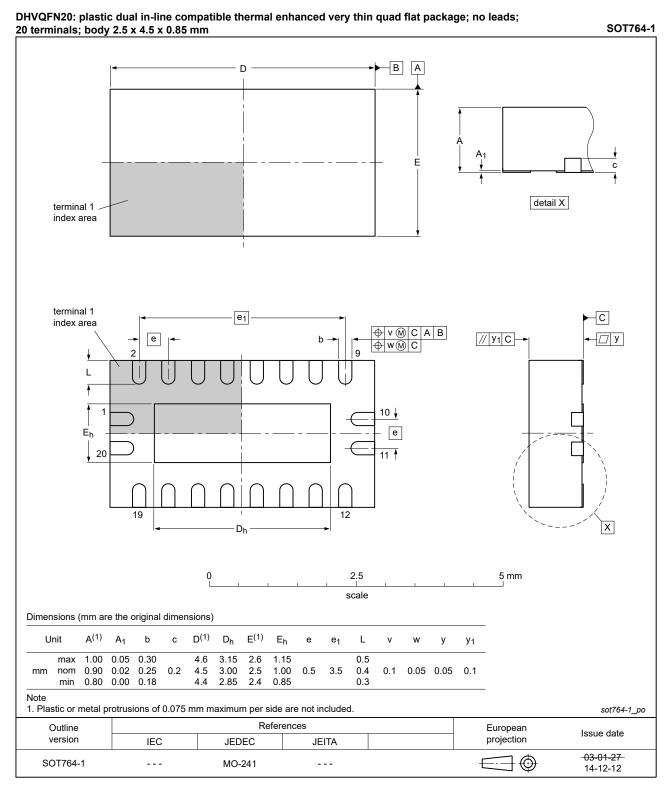


Fig. 14. Package outline SOT764-1 (DHVQFN20)

12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
MIL	Military
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT573_Q100 v.2	20200713	Product data sheet	-	74AHC_AHCT573_Q100 v.1
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. <u>Section 1</u> and <u>Section 2</u> updated. <u>Table 4</u>: Derating values for P_{tot} total power dissipation have been updated. 			
	 <u>Table 6</u>: Conditions for I_{OZ} corrected. Package outline drawing of SOT764-1 (<u>Fig. 14</u>) updated. 			
74AHC_AHCT573_Q100 v.1	20130610	Product data sheet	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

Definitions

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Octal D-type transparent latch; 3-state

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